

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|-------|--|---|------------------|---------|------------------|
| S101 | 606 | pattern\$6 near15 pitch near5 different and semiconductor | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 18:28 |
| S100 | 1736 | pattern\$6 near15 pitch near5 different | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 18:28 |
| S99 | 23374 | pattern\$6 near15 pitch | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 18:28 |
| S103 | 2 | "6498048".pn. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 18:33 |
| S102 | 275 | pattern\$6 near15 pitch near5 different and semiconductor and @py<"2003" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 18:38 |
| S104 | 6 | pattern\$6 near15 pitch near5 different and semiconductor and @py<"2003" and ("iii-v" or gan or gallium near2 nitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 18:40 |
| S105 | 20 | pattern\$6 near15 pitch near5 different and ("iii-v" or gan or gallium near2 nitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 19:09 |
| S106 | 25 | pattern\$6 near5 different same overlap\$6 and ("iii-v" or gan or gallium near2 nitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 19:12 |
| S107 | 308 | pattern\$5 near16 etch\$6 near17 (gan or gallium near2 nitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 19:46 |

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| S10 8 | 13 | repeat\$6 near16 (elo or epitax\$5 near2 lateral near2 overgrow\$5) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 19:47 |
| S10 9 | 467 | (elo or epitax\$5 near2 lateral near2 overgrow\$5) near15 (gan or gallium near2 nitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/26 19:48 |
| S11 0 | 30 | (elo or epitax\$5 near2 lateral near2 overgrow\$5) near15 (gan or gallium near2 nitride) near15 again | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 09:42 |
| L2 | 24 | (elo or epitax\$5 near2 lateral near2 overgrow\$5) near15 trench | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 09:42 |
| L1 | 2 | (elo or epitax\$5 near2 lateral near2 overgrow\$5) near5 partial | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 09:42 |
| L5 | 43 | (US-20010003019-\$ or US-20020024115-\$ or US-20020011599-\$ or US-20010020440-\$ or US-20030073315-\$ or US-20010010941-\$ or US-20010004488-\$).did. or (US-5425043-\$ or US-4751711-\$ or US-5745515-\$ or US-5629532-\$ or US-5326719-\$ or US-5446752-\$ or US-5514885-\$ or US-6271104-\$ or US-6294440-\$ or US-5453405-\$ or US-5274727-\$ or US-5821570-\$ or US-4555622-\$ or US-4952526-\$ or US-4066482-\$ or US-6255189-\$ or US-5300379-\$ or US-5922216-\$ or US-6358854-\$ or US-5856702-\$ or US-6331369-\$ or US-5928801-\$ or US-5691239-\$ or US-5881125-\$ or US-4444620-\$ or US-5358890-\$).did. or (US-5956564-\$ or US-4803691-\$ or US-5559058-\$ or US-6388731-\$ or US-4843563-\$ or US-6741732-\$ or US-5672520-\$ or US-6498048-\$ or US-6463184-\$ or US-6319742-\$).did. | US-PGPUB; USPAT | OR | ON | 2006/05/30 09:46 |

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| L6 | 33 | 5 and (gan or gallium near2 nitride or "iii-v") | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:11 |
| L9 | 275 | plurality near2 devices near15 wafer and scribe near2 line | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:12 |
| L8 | 9 | plurality near2 devices near15 wafer near15 sapphire | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:12 |
| L7 | 2327 | plurality near2 devices near15 wafer | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:12 |
| L10 | 33 | plurality near2 devices near15 wafer and scribe near2 line and @py<"1999" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:13 |
| L11 | 29 | plurality near2 devices near15 wafer same (led or light near2 emitting near2 diode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:24 |
| L12 | 52 | linthicum.in. and gan | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:28 |
| L14 | 142 | wafer same plurality near5 device near5 laser | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:29 |
| L13 | 407 | wafer same plurality near5 device same laser | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:29 |
| L15 | 35 | wafer same plurality near5 device near5 laser and @py<"2000" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 10:32 |

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| L16 | 49 | wafer same array near5 device near5 laser and @py<"2000" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 11:28 |
| L18 | 1 | "6294440".pn. and cladding | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 12:00 |
| L17 | 7 | wafer same device near5 laser same productivity and @py<"2000" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 12:00 |
| S2 | 71 | (morita near2 etsuo).in. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 12:07 |
| L19 | 74 | (morita near2 etsuo).in. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/05/30 12:07 |